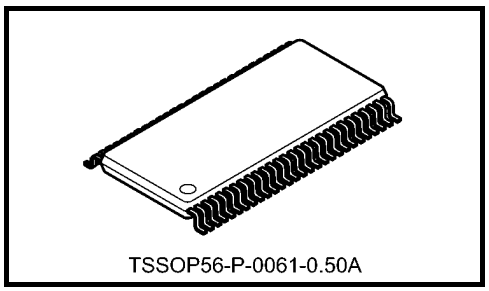
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VCX162841FT

## Low-Voltage 20-Bit D-Type Latch with 3.6-V Tolerant Inputs and Outputs




Weight: 0.25 g (typ.)

The TC74VCX162841FT is a high-performance CMOS 20-bit D-type latch. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

The TC74VCX162841FT can be used as two 10-bit latches or one 20-bit latch. The 20 latches are transparent D-type latches. The device has noninverting data (D) inputs and provides true data at its outputs. While the latch-enable (1LE or 2LE) input is high, the Q outputs of the corresponding 10-bit latch follow the D inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs. When the $\overline{OE}$ input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

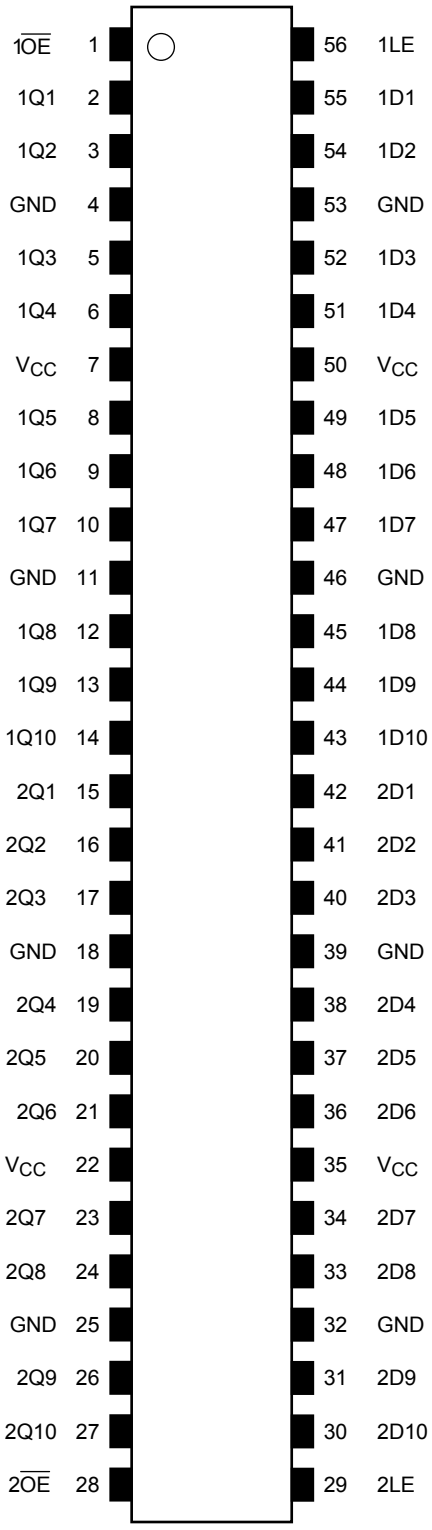
The 26-Ω series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.

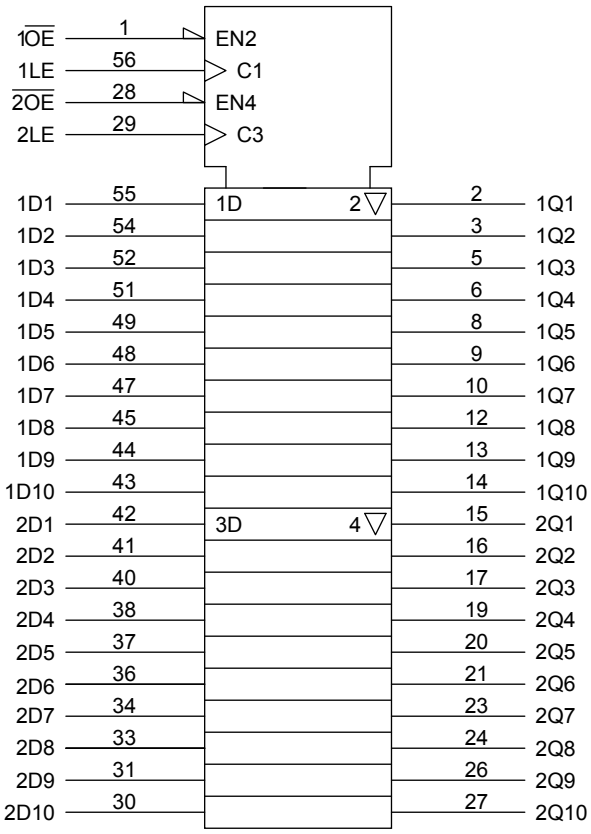
## Features

- 26-Ω series resistors on outputs
- Low-voltage operation: $V_{CC}$ = 1.8 to 3.6 V
- High-speed operation: $t_{pd}$ = 3.9 ns (max) ($V_{CC}$ = 3.0 to 3.6 V)
  : $t_{pd}$ = 4.8 ns (max) ($V_{CC}$ = 2.3 to 2.7 V)
  : $t_{pd}$ = 9.6 ns (max) ($V_{CC}$ = 1.8 V)
- Output current: $I_{OH}/I_{OL}$ = ±12 mA (min) ($V_{CC}$ = 3.0 V)
  : $I_{OH}/I_{OL}$ = ±8 mA (min) ($V_{CC}$ = 2.3 V)
  : $I_{OH}/I_{OL}$ = ±4 mA (min) ($V_{CC}$ = 1.8 V)
- Latch-up performance: –300 mA
- ESD performance: Machine model ≥ ±200 V
  Human body model ≥ ±2000 V
- Package: TSSOP
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

## Pin Assignment (top view)




## IEC Logic Symbol



## Truth Table (each 10-bit latch)

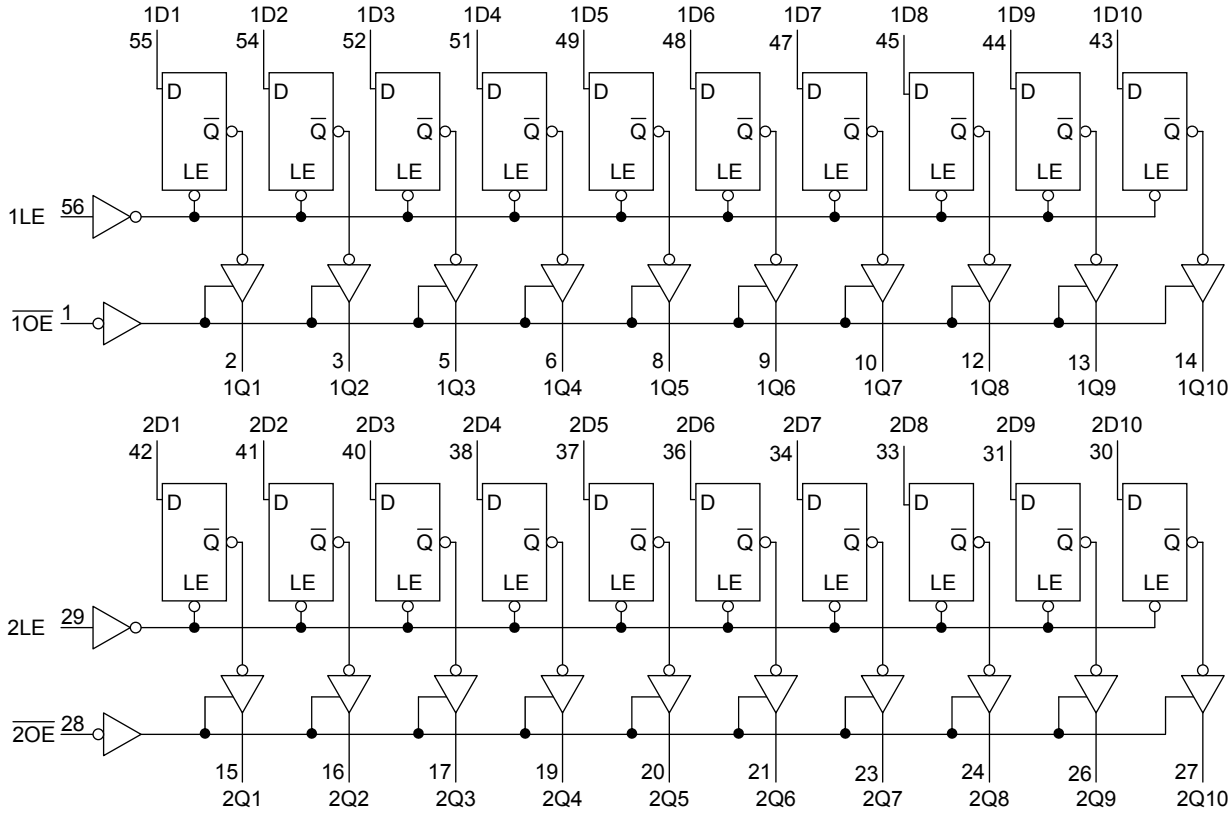
| Input | | | Output |
|---|---|---|---|
| $\overline{OE}$ | LE | D | Q |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Qn |
| H | X | X | Z |

X: Don’t care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

## System Diagram



## Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Power supply voltage | $V_{CC}$ | −0.5 to 4.6 | V |
| DC input voltage | $V_{IN}$ | −0.5 to 4.6 | V |
| DC output voltage | $V_{OUT}$ | −0.5 to 4.6 (Note 2) | V |
| | | −0.5 to $V_{CC}$ + 0.5 (Note 3) | |
| Input diode current | $I_{IK}$ | −50 | mA |
| Output diode current | $I_{OK}$ | ±50 (Note 4) | mA |
| DC output current | $I_{OUT}$ | ±50 | mA |
| Power dissipation | $P_D$ | 400 | mW |
| DC $V_{CC}$/ground current per supply pin | $I_{CC}/I_{GND}$ | ±100 | mA |
| Storage temperature | $T_{stg}$ | −65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. $I_{OUT}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$

## Operating Ranges (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Power supply voltage | $V_{CC}$ | 1.8 to 3.6 | V |
| | | 1.2 to 3.6 (Note 2) | |
| Input voltage | $V_{IN}$ | −0.3 to 3.6 | V |
| Output voltage | $V_{OUT}$ | 0 to 3.6 (Note 3) | V |
| | | 0 to $V_{CC}$ (Note 4) | |
| Output current | $I_{OH}/I_{OL}$ | ±12 (Note 5) | mA |
| | | ±8 (Note 6) | |
| | | ±4 (Note 7) | |
| Operating temperature | $T_{opr}$ | −40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 10 (Note 8) | ns/V |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: OFF state

Note 4: High or low state

Note 5: $V_{CC}$ = 3.0 to 3.6 V

Note 6: $V_{CC}$ = 2.3 to 2.7 V

Note 7: $V_{CC}$ = 1.8 V

Note 8: $V_{IN}$ = 0.8 to 2.0 V, $V_{CC}$ = 3.0 V

## Electrical Characteristics

### DC Characteristics (Ta = –40 to 85°C, 2.7 V < $V_{CC}$ ≦ 3.6 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 2.7 to 3.6 | 2.0 | — | V |
| | L-level | $V_{IL}$ | — | | 2.7 to 3.6 | — | 0.8 | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –100 μA | 2.7 to 3.6 | $V_{CC}$ – 0.2 | — | V |
| | | | | $I_{OH}$ = –6 mA | 2.7 | 2.2 | — | |
| | | | | $I_{OH}$ = –8 mA | 3.0 | 2.4 | — | |
| | | | | $I_{OH}$ = –12 mA | 3.0 | 2.2 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 2.7 to 3.6 | — | 0.2 | |
| | | | | $I_{OL}$ = 6 mA | 2.7 | — | 0.4 | |
| | | | | $I_{OL}$ = 8 mA | 3.0 | — | 0.55 | |
| | | | | $I_{OL}$ = 12 mA | 3.0 | — | 0.8 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 2.7 to 3.6 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 2.7 to 3.6 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 2.7 to 3.6 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 2.7 to 3.6 | — | ±20.0 | |
| Increase in $I_{CC}$ per input | | $\Delta I_{CC}$ | $V_{IH}$ = $V_{CC}$ – 0.6 V | | 2.7 to 3.6 | — | 750 | |

### DC Characteristics (Ta = –40 to 85°C, 2.3 V ≦ $V_{CC}$ ≦ 2.7 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 2.3 to 2.7 | 1.6 | — | V |
| | L-level | $V_{IL}$ | — | | 2.3 to 2.7 | — | 0.7 | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = –100 μA | 2.3 to 2.7 | $V_{CC}$ – 0.2 | — | V |
| | | | | $I_{OH}$ = –4 mA | 2.3 | 2.0 | — | |
| | | | | $I_{OH}$ = –6 mA | 2.3 | 1.8 | — | |
| | | | | $I_{OH}$ = –8 mA | 2.3 | 1.7 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 2.3 to 2.7 | — | 0.2 | |
| | | | | $I_{OL}$ = 6 mA | 2.3 | — | 0.4 | |
| | | | | $I_{OL}$ = 8 mA | 2.3 | — | 0.6 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 2.3 to 2.7 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 2.3 to 2.7 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 2.3 to 2.7 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 2.3 to 2.7 | — | ±20.0 | |

## DC Characteristics (Ta = −40 to 85°C, 1.8 V ≦ $V_{CC}$ < 2.3 V)

| Characteristics | | Symbol | Test Condition | | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|---|---|
| Input voltage | H-level | $V_{IH}$ | — | | 1.8 to 2.3 | 0.7 × $V_{CC}$ | — | V |
| | L-level | $V_{IL}$ | — | | 1.8 to 2.3 | — | 0.2 × $V_{CC}$ | |
| Output voltage | H-level | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = −100 μA | 1.8 | $V_{CC}$ − 0.2 | — | V |
| | | | | $I_{OH}$ = −4 mA | 1.8 | 1.4 | — | |
| | L-level | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 100 μA | 1.8 | — | 0.2 | |
| | | | | $I_{OL}$ = 4 mA | 1.8 | — | 0.3 | |
| Input leakage current | | $I_{IN}$ | $V_{IN}$ = 0 to 3.6 V | | 1.8 | — | ±5.0 | μA |
| 3-state output OFF state current | | $I_{OZ}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$<br>$V_{OUT}$ = 0 to 3.6 V | | 1.8 | — | ±10.0 | μA |
| Power-off leakage current | | $I_{OFF}$ | $V_{IN}$, $V_{OUT}$ = 0 to 3.6 V | | 0 | — | 10.0 | μA |
| Quiescent supply current | | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 1.8 | — | 20.0 | μA |
| | | | $V_{CC}$ ≦ ($V_{IN}$, $V_{OUT}$) ≦ 3.6 V | | 1.8 | — | ±20.0 | |

## AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500\ \Omega$) (Note 1)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Min | Max | Unit |
|---|---|---|---|---|---|---|
| Propagation delay time (D-Q) | $t_{pLH}$ $t_{pHL}$ | Figure 1, Figure 2 | 1.8 | 1.5 | 9.6 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.8 | |
| | | | 3.3 ± 0.3 | 0.6 | 3.9 | |
| Propagation delay time (LE-Q) | $t_{pLH}$ $t_{pHL}$ | Figure 1, Figure 2 | 1.8 | 1.5 | 9.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 5.8 | |
| | | | 3.3 ± 0.3 | 0.6 | 4.4 | |
| 3-state output enable time | $t_{pZL}$ $t_{pZH}$ | Figure 1, Figure 3 | 1.8 | 1.5 | 9.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 5.9 | |
| | | | 3.3 ± 0.3 | 0.6 | 4.3 | |
| 3-state output disable time | $t_{pLZ}$ $t_{pHZ}$ | Figure 1, Figure 3 | 1.8 | 1.5 | 8.8 | ns |
| | | | 2.5 ± 0.2 | 0.8 | 4.9 | |
| | | | 3.3 ± 0.3 | 0.6 | 4.3 | |
| Minimum pulse width (LE) | $t_{W\ (H)}$ | Figure 1, Figure 2 | 1.8 | 4.0 | — | ns |
| | | | 2.5 ± 0.2 | 1.5 | — | |
| | | | 3.3 ± 0.3 | 1.5 | — | |
| Minimum setup time | $t_s$ | Figure 1, Figure 2 | 1.8 | 2.5 | — | ns |
| | | | 2.5 ± 0.2 | 1.5 | — | |
| | | | 3.3 ± 0.3 | 1.5 | — | |
| Minimum hold time | $t_h$ | Figure 1, Figure 2 | 1.8 | 1.0 | — | ns |
| | | | 2.5 ± 0.2 | 1.0 | — | |
| | | | 3.3 ± 0.3 | 1.0 | — | |
| Output to output skew | $t_{osLH}$ $t_{osHL}$ | (Note 2) | 1.8 | — | 0.5 | ns |
| | | | 2.5 ± 0.2 | — | 0.5 | |
| | | | 3.3 ± 0.3 | — | 0.5 | |

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.
($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

## Dynamic Switching Characteristics

**(Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500\ \Omega$)**

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Typ. | Unit |
|---|---|---|---|---|---|
| Quiet output maximum dynamic $V_{OL}$ | $V_{OLP}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | 0.15 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | 0.25 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | 0.35 | |
| Quiet output minimum dynamic $V_{OL}$ | $V_{OLV}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | −0.15 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | −0.25 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | −0.35 | |
| Quiet output minimum dynamic $V_{OH}$ | $V_{OHV}$ | $V_{IH}$ = 1.8 V, $V_{IL}$ = 0 V (Note) | 1.8 | 1.55 | V |
| | | $V_{IH}$ = 2.5 V, $V_{IL}$ = 0 V (Note) | 2.5 | 2.05 | |
| | | $V_{IH}$ = 3.3 V, $V_{IL}$ = 0 V (Note) | 3.3 | 2.65 | |

Note: Parameter guaranteed by design.

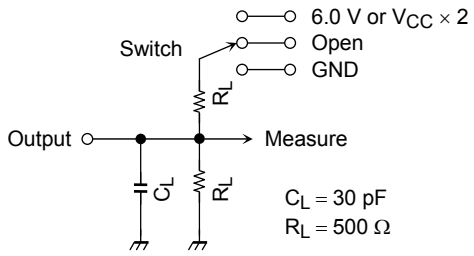
## Capacitive Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Typ. | Unit |
|---|---|---|---|---|---|
| Input capacitance | $C_{IN}$ | — | 1.8, 2.5, 3.3 | 6 | pF |
| Output capacitance | $C_O$ | — | 1.8, 2.5, 3.3 | 7 | pF |
| Power dissipation capacitance | $C_{PD}$ | $f_{IN}$ = 10 MHz (Note) | 1.8, 2.5, 3.3 | 20 | pF |

Note: $C_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/20$ (per bit)

## AC Test Circuit




| Parameter | Switch | |
|---|---|---|
| $t_{pLH}$, $t_{pHL}$ | Open | |
| $t_{pLZ}$, $t_{pZL}$ | 6.0 V<br>$V_{CC} \times 2$ | @$V_{CC}$ = 3.3 ± 0.3 V<br>@$V_{CC}$ = 2.5 ± 0.2 V<br>@$V_{CC}$ = 1.8 V |
| $t_{pHZ}$, $t_{pZH}$ | GND | |

**Figure 1 $t_{pLH}$, $t_{pHL}$, $t_w$, $t_s$, $t_h$**

## AC Waveform

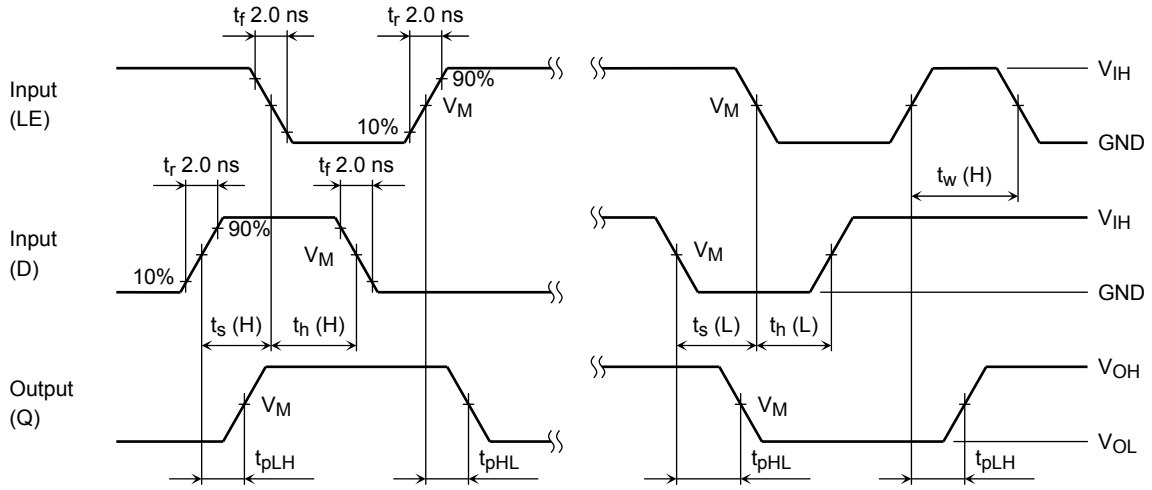



**Figure 2 $t_{pLH}$, $t_{pHL}$, $t_w$, $t_s$, $t_h$**

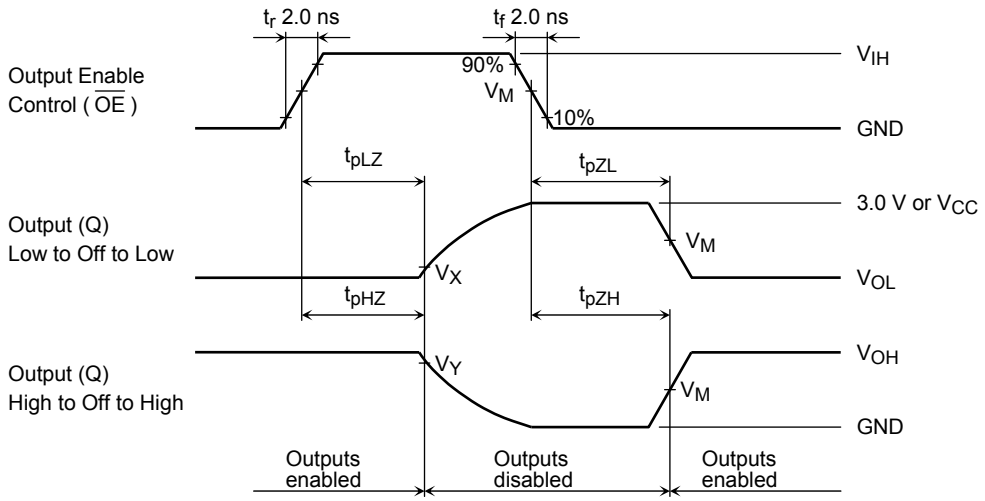
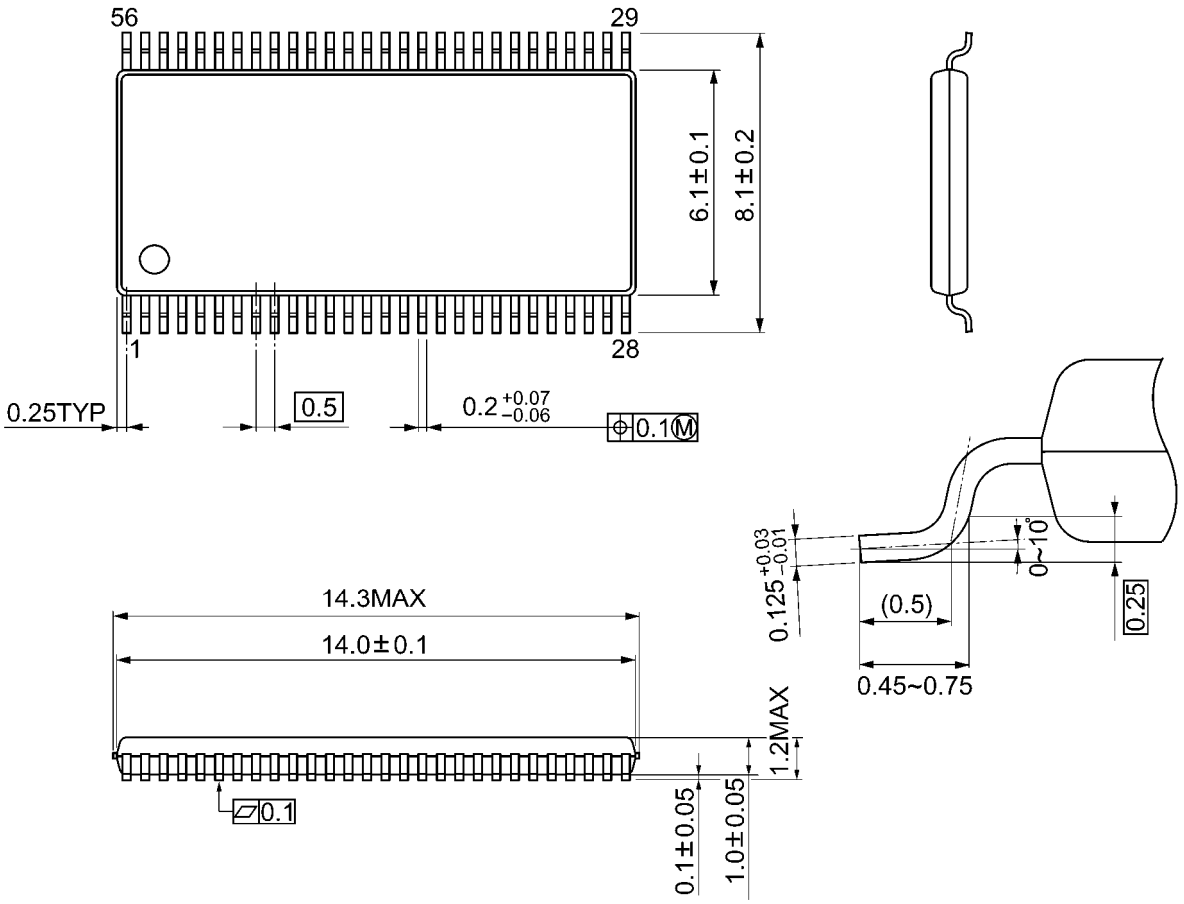



**Figure 3 $t_{pLZ}$, $t_{pHZ}$, $t_{pZL}$, $t_{pZH}$**

| Symbol | $V_{CC}$ | | |
|---|---|---|---|
| | 3.3 ± 0.3 V | 2.5 ± 0.2 V | 1.8 V |
| $V_{IH}$ | 2.7 V | $V_{CC}$ | $V_{CC}$ |
| $V_M$ | 1.5 V | $V_{CC}/2$ | $V_{CC}/2$ |
| $V_X$ | $V_{OL}$ + 0.3 V | $V_{OL}$ + 0.15 V | $V_{OL}$ + 0.15 V |
| $V_Y$ | $V_{OH}$ − 0.3 V | $V_{OH}$ − 0.15 V | $V_{OH}$ − 0.15 V |

## Package Dimensions

TSSOP56-P-0061-0.50A Unit: mm




Weight: 0.25 g (typ.)

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